

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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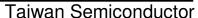
Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China











N-Channel Power MOSFET

100V, 6.5A, 95mΩ

FEATURES

- · Fast switching
- Pb-free plating
- RoHS compliant
- Halogen-free mold compound

APPLICATION

- Networking
- Load Switch
- Lighting

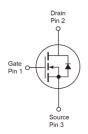
| KEY PERFORMANCE PARAMETERS | | | |
|----------------------------|------------------------|-------|------|
| PARAMETER | | VALUE | UNIT |
| $V_{	t DS}$ | | 100 | V |
| R _{DS(on)} (max) | V _{GS} = 10V | 95 | • |
| | V _{GS} = 4.5V | 110 | mΩ |
| Q_g | | 9.3 | nC |











Notes: Moisture sensitivity level: level 3. Per J-STD-020

| ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted) | | | | | |
|--|------------------------|-----------------|--------------|------|--|
| PARAMETER | | SYMBOL | LIMIT | UNIT | |
| Drain-Source Voltage | | V_{DS} | 100 | V | |
| Gate-Source Voltage | | V_{GS} | ±20 | V | |
| Continuous Drain Current (Note 1) | Γ _C = 25°C | Ι _D | 6.5 | Α | |
| Continuous Drain Current | Γ _C = 100°C | | 4.1 | | |
| Pulsed Drain Current (Note 2) | | I _{DM} | 26 | Α | |
| Total Power Dissipation @ T _C = 25°C | | P_{DTOT} | 9 | W | |
| Operating Junction and Storage Temperature Range | | T_J,T_STG | - 55 to +150 | °C | |

| THERMAL PERFORMANCE | | | | |
|--|------------------|-------|------|--|
| PARAMETER | SYMBOL | LIMIT | UNIT | |
| Junction to Case Thermal Resistance | R _{eJC} | 14 | °C/W | |
| Junction to Ambient Thermal Resistance | $R_{\Theta JA}$ | 62 | °C/W | |

Notes: $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case thermal reference is defined at the solder mounting surface of the drain pins. $R_{\Theta JA}$ is guaranteed by design while $R_{\Theta CA}$ is determined by the user's board design. $R_{\Theta JA}$ shown below for single device operation on FR-4 PCB in still air

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| ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted) | | | | | | |
|---|--|---------------------|-----|------|------|------|
| PARAMETER | CONDITIONS | SYMBOL | MIN | TYP | MAX | UNIT |
| Static (Note 3) | | | | | | |
| Drain-Source Breakdown Voltage | $V_{GS} = 0V, I_D = 250\mu A$ | BV _{DSS} | 100 | | | V |
| Gate Threshold Voltage | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$ | $V_{GS(TH)}$ | 1.2 | 1.6 | 2.5 | V |
| Gate Body Leakage | $V_{GS} = \pm 20V, V_{DS} = 0V$ | I _{GSS} | | | ±100 | nA |
| Zero Gate Voltage Drain Current | $V_{DS} = 100V, V_{GS} = 0V$ | I _{DSS} | | | 1 | μΑ |
| Drain-Source On-State Resistance | $V_{GS} = 10V, I_D = 5A$ | 1 | | 80 | 95 | mΩ |
| | $V_{GS} = 4.5V, I_D = 3A$ | $R_{DS(on)}$ | | 85 | 110 | |
| Dynamic (Note 4) | | | | | | |
| Total Gate Charge | $V_{DS} = 48V, I_{D} = 5A,$ $V_{GS} = 10V$ | Q_g | | 9.3 | | |
| Gate-Source Charge | | Q_{gs} | | 2.1 | | nC |
| Gate-Drain Charge | | Q_{gd} | | 1.8 | | |
| Input Capacitance | $V_{DS} = 50V, V_{GS} = 0V,$ | C _{iss} | | 1480 | | |
| Output Capacitance | | C _{oss} | | 480 | | pF |
| Reverse Transfer Capacitance | f = 1.0MHz | C_{rss} | | 35 | | |
| Gate Resistance | F = 1MHz, open drain | R_g | | 1.3 | | Ω |
| Switching (Note 5) | | | | | | |
| Turn-On Delay Time | | t _{d(on)} | | 2.9 | | |
| Turn-On Rise Time | $V_{DD} = 30V,$ $R_{GEN} = 3.3\Omega,$ $I_{D} = 1A, V_{GS} = 10V,$ | t _r | | 9.5 | | |
| Turn-Off Delay Time | | t _{d(off)} | | 18.4 | | ns |
| Turn-Off Fall Time | $\frac{1}{1} = 1 \text{A}, \text{V}_{\text{GS}} = 10 \text{V},$ | t _f | | 5.3 | | |
| Source-Drain Diode (Note 3) | | | | | | |
| Forward On Voltage | $I_S = 3.3A, V_{GS} = 0V$ | V_{SD} | | | 1 | V |
| Continuous Drain-Source Diode | V V 0V 5 | I _S | | | 6.5 | Α |
| Pulse Drain-Source Diode | V _G =V _D =0V, Force Current | I _{SM} | | | 26 | Α |

Notes:

- 1. Current limited by package
- 2. Pulse width limited by the maximum junction temperature
- 3. Pulse test: PW \leq 300 μ s, duty cycle \leq 2%
- 4. For DESIGN AID ONLY, not subject to production testing.
- 5. Switching time is essentially independent of operating temperature.



Taiwan Semiconductor

ORDERING INFORMATION (EXAMPLE)

| PART NO. | PACKAGE | PACKING |
|-----------------|---------|---------------------|
| TSM950N10CW RPG | SOT-223 | 2,500pcs / 13" Reel |

Note:

- 1. Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- 2. Halogen-free according to IEC 61249-2-21 definition

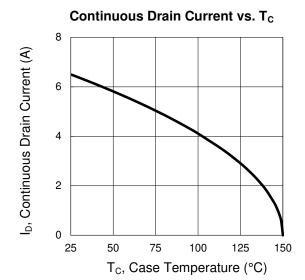
Version: C1704

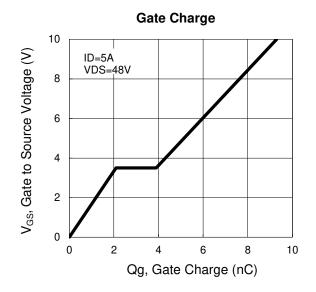
3



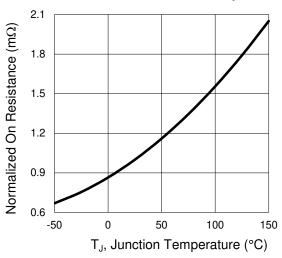
CHARACTERISTICS CURVES

(T_C = 25°C unless otherwise noted)

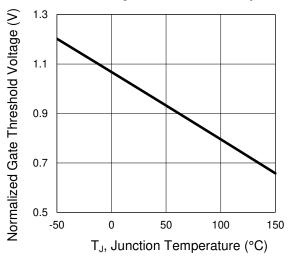




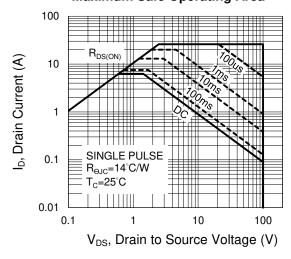
On-Resistance vs. Junction Temperature



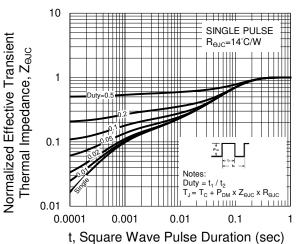
Threshold Voltage vs. Junction Temperature



Maximum Safe Operating Area



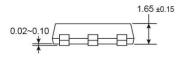
Normalized Thermal Transient Impedance Curve

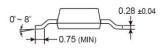




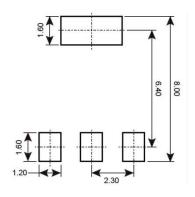
PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

SOT-223 6.5 ±0.20 3.0 ±0.10 3.0 ±0.10 2.3 (REF) 0.725 ±0.125

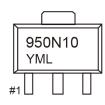




SUGGESTED PAD LAYOUT (Unit: Millimeters)



MARKING DIAGRAM



Y = Year Code

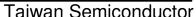
M = Month Code for Halogen Free Product

 \mathbf{O} =Jan \mathbf{P} =Feb \mathbf{Q} =Mar \mathbf{R} =Apr

S =May T =Jun U =Jul V =Aug W =Sep X =Oct Y =Nov Z =Dec

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L = Lot Code (1~9, A~Z)





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